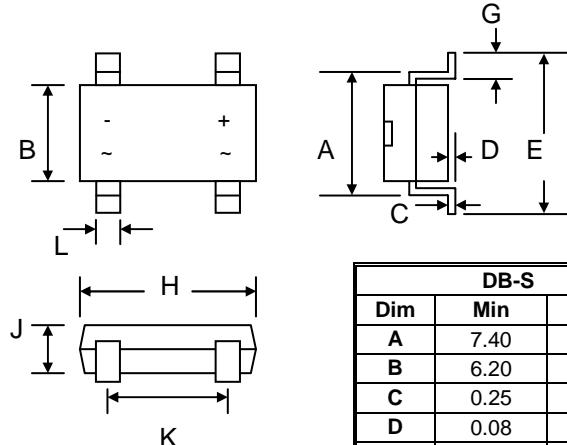




#### Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material – UL Recognition Flammability Classification 94V-O



DB-S		
Dim	Min	Max
A	7.40	7.90
B	6.20	6.50
C	0.25	—
D	0.08	0.33
E	9.30	10.30
G	1.02	1.53
H	8.00	8.51
J	2.15	3.40
K	5.00	5.20
L	0.90	1.20

All Dimensions in mm

#### Mechanical Data

- Case: DB -S, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Case
- Weight: 1.0 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version,**

#### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	DB 101S	DB 102S	DB 103S	DB 104S	DB 105S	DB 106S	DB 107S	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>								
Working Peak Reverse Voltage	V <sub>RWM</sub>	50	100	200	400	600	800	1000	V
DC Blocking Voltage	V <sub>R</sub>								
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current @T <sub>A</sub> = 40°C	I <sub>O</sub>				1.0				A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>				50				A
Forward Voltage per element @I <sub>F</sub> = 1.0A	V <sub>FM</sub>				1.1				V
Peak Reverse Current @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 125°C	I <sub>RM</sub>				5.0	500			µA
Typical Junction Capacitance per element (Note 1)	C <sub>j</sub>				25				pF
Typical Thermal Resistance per leg (Note 2)	R <sub>θJA</sub> R <sub>θJL</sub>				40	15			°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>				-65 to +150				°C

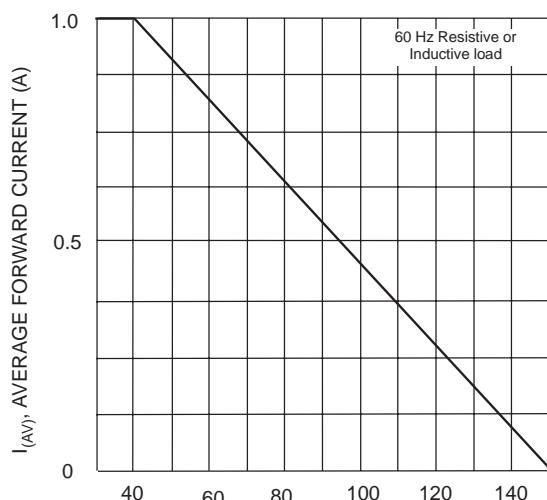
Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Mounted on PC board with 13mm<sup>2</sup> copper pad.

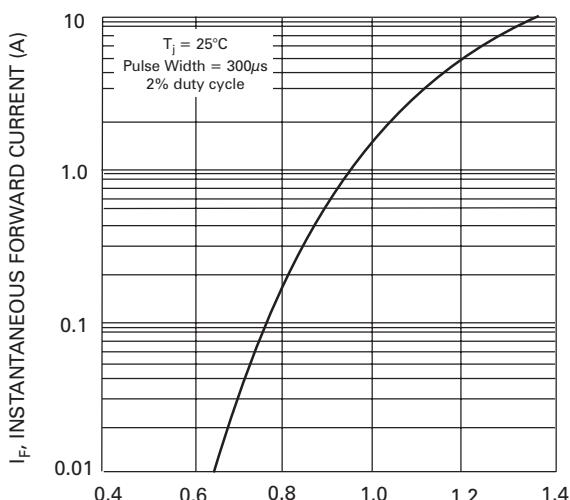


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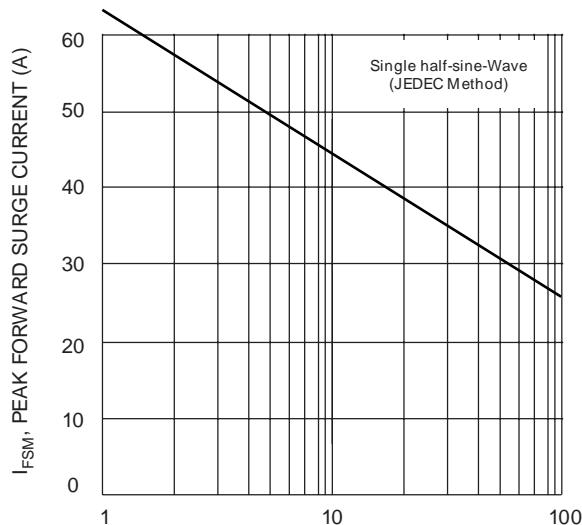
**DB101S – DB107S**



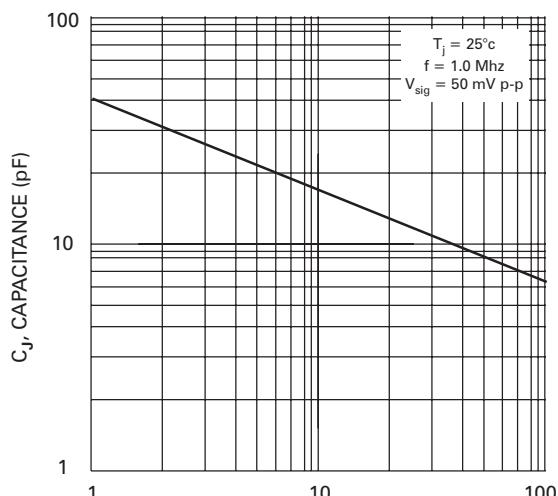
T<sub>A</sub>, AMBIENT TEMPERATURE (°C)  
Fig. 1 Output Current Derating Curve



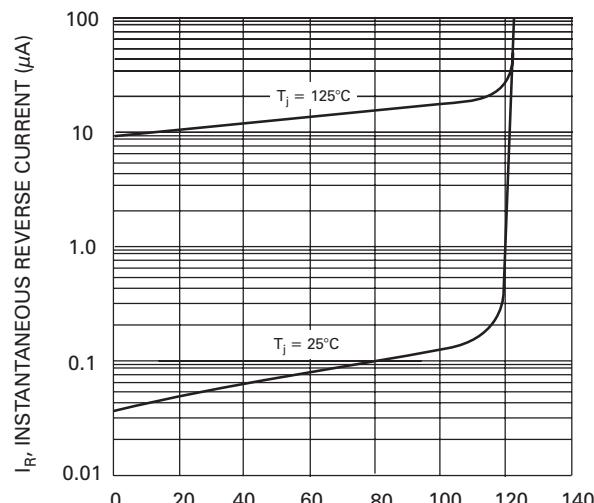
V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V)  
Fig. 2 Typ Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz  
Fig. 3 Max Non-Repetitive Peak Forward Surge Current



V<sub>R</sub>, REVERSE VOLTAGE (V)  
Fig. 4 Typ Junction Capacitance (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)  
Fig. 5 Typ Reverse Characteristics (per element)